CentralSemiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors

CR12F SERIES

12 AMP FAST RECOVERY RECTIFIER

100 THRU 1000 VOLTS

JEDEC DO-4 CASE

FEATURES

12 Amps at 150°C Hermetic Seal Stud Mounting 200 Amps surge current
Reliable internal construction
Extensive Temperature Range

DESCRIPTION

The CENTRAL SEMICONDUCTOR 12 ampere stud mounted Fast Recovery Silicon Rectifier is a high quality, well constructed, highly reliable component designed for use in all types of military, commercial, industrial, entertainment, computer, and automotive applications. Because of its superior electrical characteristics, this rectifier family is used as a universal replacement for many other rectifiers.

MAXIMUM RATINGS (T_C=25°C unless otherwsie noted)

		CR12F	CR12F	CR12F	CR12F	CR12F	CR12F	UNIT
	SYMBOL	-010	-020	-040	-060	-080	-100	
Peak Repetitive Reverse Voltage	VRRM	100	200	400	600	800	1000	V
DC Blocking Voltage	٧R	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR (RMS)	70	140	280	420	560	700	٧
Average Forward Current $(T_C=150^{\circ}C)$	10			1	2			Α
Peak Forward Surge Current Operating and Storage	IFSM			20	00			А
Junction Temperature	TJ,T _{st}	9		-65 TC	+200			°C

ELECTRICAL CHARACTERISTICS (T_C=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
VF	I _F =12A		1.4	
I _R	VR=Rated VRRM		25	μA
l'R	VR=Rated VRRM, Tc=100°C		3.0	mA
trr	I _F =1.0A to V _R =30V (100V thru 600V)		200	ns
trr	1 _F =1.0A to V _R =30V (800V thru 1000V)		300	ns

Normal Polarity: Cathode to stud (case)

For reverse polarity add "R" to suffix. EX: CR12-040R